

Detectors for mm-Waves and Terahertz (and how these might be used for EO)

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Introduction



- Limit discussion to rectifying THz video / power detectors
- Detector dimensions << wavelength: need antennas to couple THz power to devices
- Spectral coverage < 50 GHz to ≈ 4 THz targeted
- Based on ≈ 1 µm InGaAs Schottky diodes
- Very fast, 300 K operation
- Applications
 - Lab spectroscopy
 - Imaging
 - Diagnostics on particle accelerators
 - Remote sensing radiometers, when used with low noise amplifiers



InGaAs Detector Diodes





- Development from MMT's GaAs Schottky devices for mixers and multipliers
- Air bridge & vertical walls: low parasitic capacitance link to ≈ 1 µm dia. anode
- External wafer growth
- In-house metals and optical lithography
- Dedicated equipment
 - Emphasis on reproducibility and yield

Zero Bias Diode Characteristics



- Asymmetric I(V) at 0 V provides detection signal
- No bias = no shot noise
- Junction resistance at 0 V $\approx k\Omega$

- Diode dimensions << wavelength
 - Need method to couple RF power to the device
- Embed in waveguide or use planar antenna and lens





Measured I(V) for a set of InGaAs diodes

Quasi-optical detectors





Broadband sinuous antenna with diode chip in centre Antenna substrate on rear of lens

Front view. Lens is 10 mm in diameter

Performance: Linearity and Spectral





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Waveguide Devices





Performance: Noise





- W-band waveguide device presented
- 1/f point ≈ 500 Hz
- Noise floor of 5 pW/ \sqrt{Hz}
 - Need NEΔT < 1 K for EO.....

Application in Radiometry (1)



 Typical front-end receiver → Conventional heterodyne downconverter based on Schottky & MMIC technology



- Complicated receiver approach, with Schottky devices in mixer and xN multiplication stages in Local Oscillator
- Diode detector noise of 5 pW/ \sqrt{Hz} is not low enough to give required NE Δ T, < 1 K for EO

Application in Radiometry (2)



• Solution: integrate detector diodes with low noise amplifiers



- LNA's are available to frequencies > 200 GHz
- Bandpass resonant cavity filters have insertion loss < 1 dB (e.g. U. Birmingham)
- Approach only suitable when spectral resolution of line not required
- Now show LNA examples taken from our work for MetOP
 - Used with mixers, not direct detectors, in MetOp

MetOp Low Noise amplifiers



Requirements for MetOp

- Stringent receiver Noise Figure requirements:
 - 166 GHz channels: < 5 dB
 - 183 GHz channels: < 5 dB</p>
 - 229 GHz channel: < 7 dB
 - Gain: >20 dB
- Sideband balance: gain deviation between receiver sidebands has to be < 1 dB on average</p>
- RAL's LNAs widely meet and exceed those requirements
 - MMICs based on 50 nm mHEMT process from Fraunhofer IAF (D)
 - 166 & 183 GHz Common source design, 3 stages
 - 229 GHz Cascode design
 - RAL undertakes the amplifier packaging and test
- Extensive work performed on design and optimisation of this design together with Fraunhofer IAF (DE), RPG (DE), ESA and ADS (UK/Fr/Es)
- Work fully presented by Simon Rea, Proc. International Symposium on Space Terahertz Technology, Cologne, 2017

LNA Measurement results





LNAs – internal view



LNA Packaging by RAL

- Quartz transitions from coplanar waveguide to hollow rectangular waveguides
- DC bias circuit is flexibly tuneable to optimise all 3 amplifier stages independently
- Waveguide equaliser to remove sideband imbalance



Summary



- InGaAs diodes working in quasi optical and waveguide detectors at room temperature,
- Best NEP ≈ 5 pW/√Hz below ≈ 300 GHz
- Address response roll-off at higher frequencies with smaller devices
- Would need to use with low noise amplifiers for EO
- Summarised state-of-art Met-Op SG LNAs

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Block outline



Front-End Receivers for MWS & MWI (166-229 GHz)



► Front-End Receiver → Heterodyne down-converter based on Schottky & MMIC technology



Component / Sub-Assembly	Supplier	Internal Components
RF LNA	RAL	Fraunhofer IAF MMICs
Schottky Mixers / Multipliers	RAL or RPG	Teratech Diodes; ACST Diodes
LO Chain Power Amps / doublers	RPG	ADI-Hittite MMICs
LO Chain passive modules	RPG	
DRO	L3-Miteq	Custom: ~30 GHz, 22dBm
IF LNA	L3-Miteq	SAFS series
DC Electronics (EPC)	RAL	Various
RF Electronics (IPU)	RAL/Spur	Various

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183 GHz FERX Schematic



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Introduction



- MetOp Second Generation satellites in development
 - Global weather forecasting data 2020-2040
 - Two satellites (Sat-A & Sat-B)
 - Three sets of satellites, each with 7.5 year nominal lifetime
 - Three passive millimetre-wave instruments being developed by European Industry
 - Microwave Sounder (MWS)
 - RAL to supply 166, 183, 229 GHz FERX
 - Microwave Imager (MWI)
 - RAL to supply 166, 183 GHz FERX
 - Ice Cloud Imager (ICI)
 - RAL to supply 183, 243, 325 GHz FERX

Models: EQM, PFM, FM2, FM3, Flight Spare

